

## 5P49V60

### VersaClock® 6E Programmable Clock Generator

The 5P49V60 is a commercial, programmable clock generator supporting automotive applications. Configurations may be stored in on-chip One-Time Programmable (OTP) memory or changed using I<sup>2</sup>C interface. This is Renesas' sixth generation of programmable clock technology (VersaClock 6E).

The frequencies are generated from a single reference clock. The reference clock can come from one of the two redundant clock inputs. A glitchless manual switchover function allows one of the redundant clocks to be selected during normal operation.

Two select pins allow up to four different configurations to be programmed and accessible using processor GPIOs or bootstrapping. The different selections may be used for different operating modes (full function, partial function, partial power-down), regional standards (US, Japan, Europe) or system production margin testing. The device may be configured to use one of two I<sup>2</sup>C addresses to allow multiple devices to be used in a system.

## Applications

- Automotive infotainment
- Dashboard systems
- PCI Express 1.0 / 2.0 / 3.0 / 4.0 (with spread spectrum)
- Audio/Video applications
- Camera applications
- Active antennas
- In-vehicle networking

## Features

- Flexible 1.8V, 2.5V, or 3.3V power-rails
- High-performance, low phase noise PLL, < 0.5ps RMS typical phase jitter on outputs
- Four banks of internal OTP memory
  - In-system or factory programmable
  - Two select pins accessible with processor GPIOs or bootstrapping
- I<sup>2</sup>C serial programming interface
  - 0xD0 or 0xD4 I<sup>2</sup>C address options allows multiple devices configured in a same system
- Reference LVCMOS output clock
- Four universal output pairs individually configurable:
  - Differential (LVPECL, LVDS or HCSL)
  - Two single-ended (2 LVCMOS in-phase or 180 degrees out of phase)
  - I/O V<sub>DD</sub>'s can be mixed and matched, supporting 1.8V (LVDS and LVCMOS), 2.5V, or 3.3V
- Output frequency ranges:
  - LVCMOS clock outputs: 1MHz to 200MHz
  - LVDS, LVPECL, HCSL differential clock outputs: 1MHz to 350MHz
- Redundant clock input with manual switchover
- Programmable output enable or power-down mode
- 4 × 4 mm 24-VFQFPN wettable flank package
- AEC-Q100 qualified
- -40°C to +105°C (Grade 2 equivalent) operating temperature

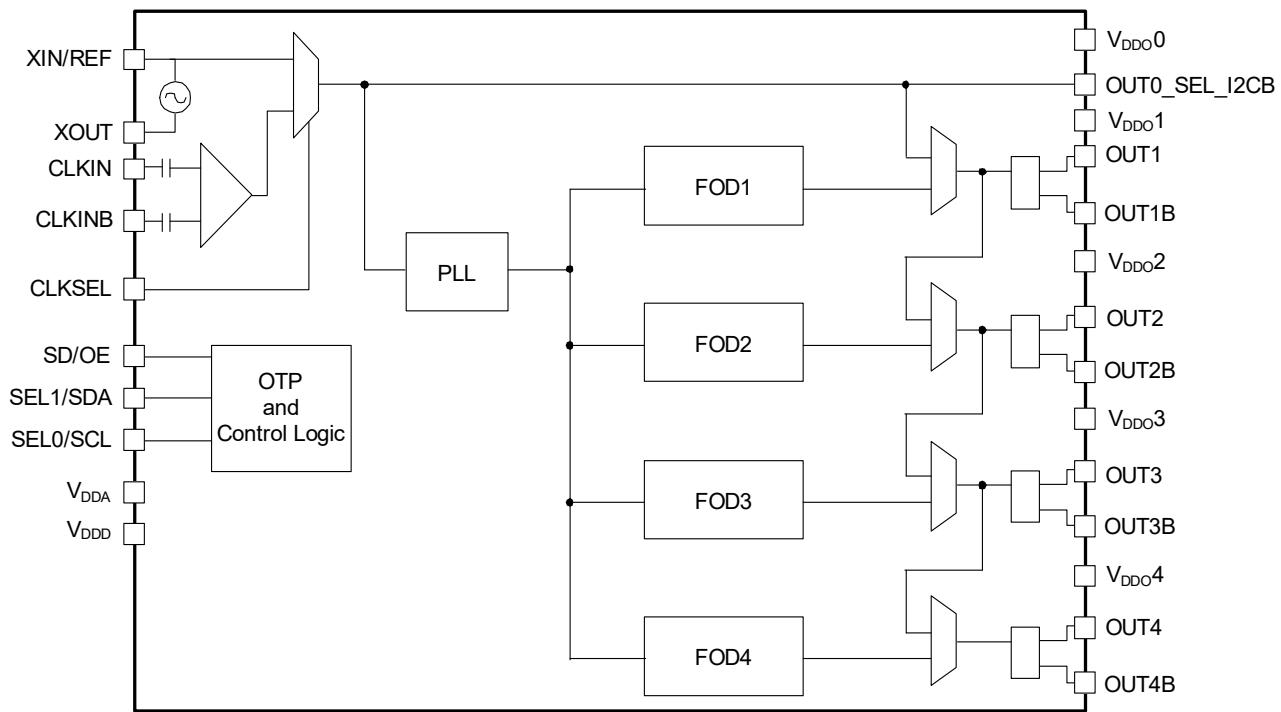
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# 1. Overview

## 1.1 Block Diagram



## 2. Pin Information

### 2.1 Pin Assignments

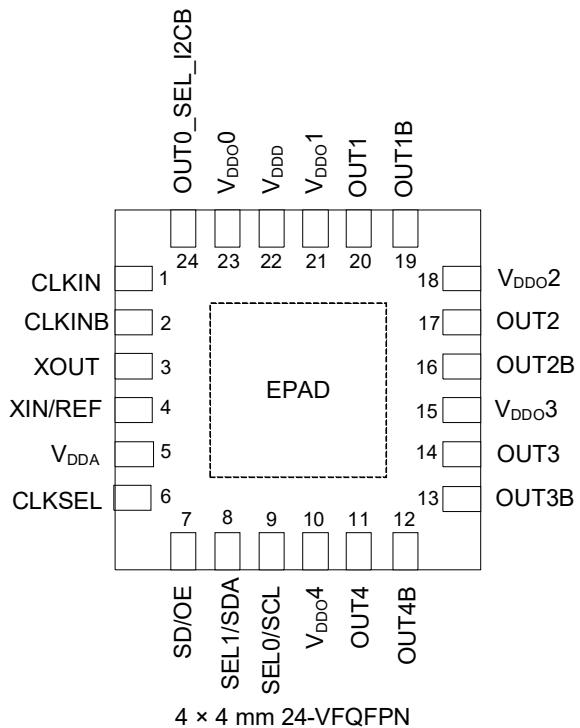


Figure 1. Pin Assignments for 4 x 4 mm 24-VFQFPN Package – Top View

### 2.2 Pin Descriptions

| Pin Number | Pin Name | Pin Type                 |                    | Description  |
|------------|----------|--------------------------|--------------------|--|
| 1          | CLKIN    | Input Internal Pull-down |                    | Differential clock input. Weak 100kΩ internal pull-down.   |
| 2          | CLKINB   | Input Internal Pull-down |                    | Complementary differential clock input. Weak 100kΩ internal pull-down.   |
| 3          | XOUT     | Output                   |                    | Crystal oscillator interface output.   |
| 4          | XIN/REF  | Input                    |                    | Crystal oscillator interface input, or single-ended LVCMOS clock input. Ensure that the input voltage is between 500mV and 1.2V. Refer to the section <a href="#">Driving XIN/REF with a CMOS Driver</a> . |
| 5          | VDDA     | Power                    |                    | Analog functions power supply pin. Connect to 1.8V to 3.3V. VDDA and VDDD should have the same voltage applied.  |
| 6          | CLKSEL   | Input                    | Internal Pull-down | Input clock select. Selects the active input reference source in manual switchover mode.<br>0 = XIN/REF, XOUT (default).<br>1 = CLKIN, CLKINB.<br>See <a href="#">Table 16</a> for more details.           |
| 7          | SD/OE    | Input                    | Internal Pull-down | Enables/disables the outputs (OE) or powers down the chip (SD).  |
| 8          | SEL1/SDA | Input                    | Internal Pull-down | Configuration select pin, or I <sup>2</sup> C SDA input as selected by OUT0_SEL_I2CB. Weak internal pull-down resistor.  |

| Pin Number | Pin Name          | Pin Type         |                       | Description  |
|------------|-------------------|------------------|-----------------------|--|
| 9          | SEL0/SCL          | Input            | Internal Pull-down    | Configuration select pin, or I <sup>2</sup> C SCL input as selected by OUT0_SEL_I2CB. Weak internal pull-down resistor.  |
| 10         | V <sub>DDO4</sub> | Power            |                       | Output power supply. Connect to 1.8 to 3.3V. Sets output voltage levels for OUT4/OUT4B.  |
| 11         | OUT4              | Output           |                       | Output clock 4. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 12         | OUT4B             | Output           |                       | Complementary output clock 4. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 13         | OUT3B             | Output           |                       | Complementary output clock 3. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 14         | OUT3              | Output           |                       | Output clock 3. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 15         | V <sub>DDO3</sub> | Power            |                       | Output power supply. Connect to 1.8 to 3.3V. Sets output voltage levels for OUT3/OUT3B.  |
| 16         | OUT2B             | Output           |                       | Complementary output clock 2. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 17         | OUT2              | Output           |                       | Output clock 2. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 18         | V <sub>DDO2</sub> | Power            |                       | Output power supply. Connect to 1.8 to 3.3V. Sets output voltage levels for OUT2/OUT2B.  |
| 19         | OUT1B             | Output           |                       | Complementary output clock 1. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 20         | OUT1              | Output           |                       | Output clock 1. Refer to the <a href="#">Output Drivers</a> section for more details.  |
| 21         | V <sub>DDO1</sub> | Power            |                       | Output power supply. Connect to 1.8 to 3.3V. Sets output voltage levels for OUT1/OUT1B.  |
| 22         | V <sub>DDD</sub>  | Power            |                       | Digital functions power supply pin. Connect to 1.8 to 3.3V. V <sub>DDA</sub> and V <sub>DDD</sub> should have the same voltage applied.  |
| 23         | V <sub>DDO0</sub> | Power            |                       | Power supply pin for OUT0_SEL_I2CB. Connect to 1.8 to 3.3V. Sets output voltage levels for OUT0.   |
| 24         | OUT0_SEL_I2CB     | Input/<br>Output | Internal<br>Pull-down | Latched input/LVCMOS output. At power-up, the voltage at the pin OUT0_SEL_I2CB is latched by the part and used to select the state of pins 8 and 9. If a weak pull-up (10kΩ) is placed on OUT0_SEL_I2CB, pins 8 and 9 will be configured as hardware select pins, SEL1 and SEL0. If a weak pull-down (10kΩ) is placed on OUT0_SEL_I2CB or it is left floating, pins 8 and 9 will act as the SDA and SCL pins of an I <sup>2</sup> C interface. After power-up, the pin acts as an LVCMOS reference output. |
| 25         | GND               | GND              |                       | Connect to ground pad.   |

### 3. Specifications

#### 3.1 Absolute Maximum Ratings

**CAUTION:** Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions can adversely impact product reliability and result in failures not covered by warranty.

**Table 1. Absolute Maximum Ratings**

| Item  | Rating                         |
|---|--------------------------------|
| Supply Voltage, $V_{DDA}$ , $V_{DDD}$ , $V_{DDO}$ | 3.465V                         |
| XIN/REF Input                                     | 1.2V                           |
| CLKIN, CLKINB Input                               | $V_{DDO}$ , 1.2V voltage swing |
| $I^2C$ Loading Current                            | 10mA                           |
| Storage Temperature, $T_{STG}$                    | -65°C to 150°C                 |

#### 3.2 ESD Ratings

| ESD Model/Test                            | Rating | Unit |
|---|--------|------|
| Human Body Model (Tested per JS-001-2017) | 2000   | V    |

#### 3.3 Recommended Operating Conditions

| Symbol    | Parameter  | Minimum | Typical | Maximum | Unit |
|-----------|--|---------|---------|---------|------|
| $V_{DDO}$ | Power supply voltage for supporting 1.8V outputs.  | 1.71    | 1.8     | 1.89    | V    |
|           | Power supply voltage for supporting 2.5V outputs.  | 2.375   | 2.5     | 2.625   | V    |
|           | Power supply voltage for supporting 3.3V outputs.  | 3.135   | 3.3     | 3.465   | V    |
| $V_{DDD}$ | Power supply voltage for core logic functions.   | 1.71    | -       | 3.465   | V    |
| $V_{DDA}$ | Analog power supply voltage. Use filtered analog power supply.                                       | 1.71    | -       | 3.465   | V    |
| $T_A$     | Operating temperature (Grade 2), ambient.  | -40     | -       | 105     | °C   |
| $C_L$     | Maximum load capacitance (3.3V LVCMOS only).   | -       | -       | 15      | pF   |
| $t_{PU}$  | Power-up time for all $V_{DD}$ s to reach minimum specified voltage (power ramps must be monotonic). | 0.05    | -       | 5       | ms   |

#### 3.4 Thermal Specifications

| Symbol        | Parameter   | Value | Unit |
|---------------|---|-------|------|
| $\theta_{JA}$ | Theta $J_A$ . Junction to air thermal impedance (0mps).   | 42    | °C/W |
| $\theta_{JB}$ | Theta $J_B$ . Junction to board thermal impedance (0mps). | 2.35  | °C/W |
| $\theta_{JC}$ | Theta $J_C$ . Junction to case thermal impedance (0mps).  | 41.8  | °C/W |

### 3.5 Electrical Specifications

Recommended operating conditions unless otherwise noted.  $V_{DDA}$ ,  $V_{DDD}$ ,  $V_{DDO0} = 3.3V \pm 5\%$ ,  $2.5V \pm 5\%$ ,  $1.8V \pm 5\%$ ,  $T_A = -40^\circ C$  to  $+105^\circ C$ , unless otherwise specified.

Table 2. Current Consumption

| Symbol           | Parameter                    | Conditions  | Minimum | Typical | Maximum | Unit |
|------------------|------------------------------|---|---------|---------|---------|------|
| $I_{DDCORE}$ [1] | Core Supply Current          | 100MHz on all outputs, 25MHz REFCLK (3.3V)            | -       | 32      | 42      | mA   |
|                  |                              | 100MHz on all outputs, 25MHz REFCLK (2.5V)            | -       | 32      | 42      |      |
|                  |                              | 100MHz on all outputs, 25MHz REFCLK (1.8V)            | -       | 31      | 42      |      |
| $I_{DDOx}$       | Output Buffer Supply Current | LVPECL, 350MHz, 3.3V $V_{DDOx}$ .                     | -       | 48      | 63      | mA   |
|                  |                              | LVPECL, 350MHz, 2.5V $V_{DDOx}$ .                     | -       | 41      | 54      | mA   |
|                  |                              | LVDS, 350MHz, 3.3V $V_{DDOx}$ .                       | -       | 26      | 32      | mA   |
|                  |                              | LVDS, 350MHz, 2.5V $V_{DDOx}$ (same setting as 3.3V). | -       | 25      | 30      | mA   |
|                  |                              | LVDS, 350MHz, 1.8V $V_{DDOx}$ .                       | -       | 23      | 27      | mA   |
|                  |                              | HCSL, 250MHz, 3.3V $V_{DDOx}$ . [2]                   | -       | 39      | 48      | mA   |
|                  |                              | HCSL, 250MHz, 2.5V $V_{DDOx}$ . [2]                   | -       | 37      | 46      | mA   |
|                  |                              | LVCMOS, 50MHz, 3.3V, $V_{DDOx}$ . [2][3]              | -       | 23      | 27      | mA   |
|                  |                              | LVCMOS, 50MHz, 2.5V, $V_{DDOx}$ . [2][3]              | -       | 20      | 24      | mA   |
|                  |                              | LVCMOS, 50MHz, 1.8V, $V_{DDOx}$ . [2][3]              | -       | 18      | 21      | mA   |
|                  |                              | LVCMOS, 200MHz, 3.3V $V_{DDOx}$ . [2][3]              | -       | 45      | 58      | mA   |
|                  |                              | LVCMOS, 200MHz, 2.5V $V_{DDOx}$ . [2][3]              | -       | 34      | 45      | mA   |
|                  |                              | LVCMOS, 200MHz, 1.8V $V_{DDOx}$ . [2][3]              | -       | 24      | 33      | mA   |
| $I_{DDPD}$       | Power Down Current           | SD asserted, I <sup>2</sup> C programming (3.3V).     | -       | 10      | 12      | mA   |
|                  |                              | SD asserted, I <sup>2</sup> C programming (2.5V).     | -       | 10      | 12      |      |
|                  |                              | SD asserted, I <sup>2</sup> C programming (1.8V).     | -       | 10      | 12      |      |

- $I_{DDCORE} = I_{DDA} + I_{DDD}$ , no loads.
- Measured into a 5" 50Ω trace with 2pF load.
- Single CMOS driver active.

Table 3. AC Timing Characteristics

| Symbol               | Parameter         | Conditions   | Minimum | Typical | Maximum | Unit |
|----------------------|-------------------|--|---------|---------|---------|------|
| $f_{IN}$ [1]         | Input Frequency   | Input frequency limit (crystal).   | 8       | -       | 40      | MHz  |
|                      |                   | Input frequency limit (CLKIN,CLKINB).  | 1       | -       | 350     | MHz  |
|                      |                   | Input frequency limit (single-ended over XIN).   | 1       | -       | 200     | MHz  |
| $f_{OUT}$ [2]        | Output Frequency  | Single-ended clock output limit (LVC MOS).   | 1       | -       | 200     | MHz  |
|                      |                   | Differential clock output limit (LVPECL/LVDS/HCSL).  | 1       | -       | 350     |      |
| $t_{DC}$ [3]         | Output Duty Cycle | Measured at $V_{DD}/2$ , all outputs except reference output, $V_{DDO} = 2.5V$ or $3.3V$ .               | 45      | 50      | 55      | %    |
|                      |                   | Measured at $V_{DD}/2$ , all outputs except reference output, $V_{DDO} = 1.8V$ .                         | 40      | 50      | 60      | %    |
|                      |                   | Measured at $V_{DD}/2$ , reference output OUT0 (5MHz–150.1MHz) with 50% duty cycle input.                | 40      | 50      | 60      | %    |
|                      |                   | Measured at $V_{DD}/2$ , reference output OUT0 (150.1MHz–200MHz) with 50% duty cycle input.              | 30      | 50      | 70      | %    |
| $t_{SKew}$           | Output Skew       | Skew between the same frequencies, with outputs using the same driver format and phase delay set to 0ns. | -       | 75      | -       | ps   |
| $t_{STARTUP}$ [4][5] | Startup Time      | Measured after all $V_{DD}$ s have risen above 90% of their target value. [6]                            | -       |         | 30      | ms   |
|                      |                   | PLL lock time from shutdown mode.  | -       | 3       | 4       | ms   |

1. Practical lower frequency is determined by loop filter settings.
2. A slew rate of 2.75V/ns or greater should be selected for output frequencies of 100MHz or higher.
3. Duty cycle is only guaranteed at maximum slew rate settings.
4. Actual PLL lock time depends on the loop configuration.
5. Includes loading the configuration bits from EPROM to PLL registers. It does not include EPROM programming/write time.
6. Power-up with temperature calibration enabled; contact Renesas if shorter lock-time is required in system.

Table 4. Input Characteristics

| Symbol   | Parameter          | Conditions   | Minimum             | Typical | Maximum             | Unit       |
|----------|--------------------|--|---------------------|---------|---------------------|------------|
| $C_{IN}$ | Input Capacitance  | CLKIN,CLKINB,CLKSEL,SD/OE,SEL1/SDA,SEL0/SCL.                     | -                   | 3       | 7                   | pF         |
| $R_{PD}$ | Pull-down Resistor | CLKSEL, SD/OE, SEL1/SDA, SEL0/SCL, CLKIN, CLKINB, OUT0_SEL_I2CB. | 100                 | -       | 350                 | k $\Omega$ |
| $V_{IH}$ | Input High Voltage | CLKSEL, SD/OE.   | $0.7 \times V_{DD}$ | -       | $V_{DD} + 0.3$      | V          |
| $V_{IL}$ | Input Low Voltage  | CLKSEL, SD/OE.<br>$V_{DDA}, V_{DD}, V_{DDO} = 3.3V$ and $2.5V$ . | GND - 0.3           | -       | $0.3 \times V_{DD}$ | V          |
|          |                    | CLKSEL, SD/OE.<br>$V_{DDA}, V_{DD}, V_{DDO} = 1.8V$ .            | GND - 0.3           | -       | 0.4                 | V          |
| $V_{IH}$ | Input High Voltage | OUT0_SEL_I2CB.   | $0.7 \times V_{DD}$ | -       | $V_{DDO} + 0.3$     | V          |
| $V_{IL}$ | Input Low Voltage  | OUT0_SEL_I2CB.   | GND - 0.3           | -       | 0.4                 | V          |
| $V_{IH}$ | Input High Voltage | XIN/REF.   | 0.5                 | -       | 1.2                 | V          |

Table 4. Input Characteristics (Cont.)

| Symbol    | Parameter            | Conditions                         | Minimum   | Typical | Maximum | Unit |
|-----------|----------------------|------------------------------------|-----------|---------|---------|------|
| $V_{IL}$  | Input Low Voltage    | XIN/REF.                           | GND - 0.3 | -       | 0.4     | V    |
| $T_R/T_F$ | Input Rise/Fall Time | CLKSEL, SD/OE, SEL1/SDA, SEL0/SCL. | -         | -       | 300     | ns   |

Table 5. CLKIN Electrical Characteristics

| Symbol      | Parameter                       | Conditions                              | Minimum | Typical | Maximum | Unit    |
|-------------|---------------------------------|---|---------|---------|---------|---------|
| $V_{SWING}$ | Input Amplitude – CLKIN, CLKINB | Peak to peak value, single-ended.       | 200     | -       | 1200    | mV      |
| $dv/dt$     | Input Slew Rate – CLKIN, CLKINB | Measured differentially.                | 0.4     | -       | 8       | V/ns    |
| $I_{IL}$    | Input Leakage Low Current       | $V_{IN} = GND$ .                        | -5      | -       | 5       | $\mu A$ |
| $I_{IH}$    | Input Leakage High Current      | $V_{IN} = 1.7V$ .                       | -       | -       | 30      | $\mu A$ |
| $DC_{IN}$   | Input Duty Cycle                | Measurement from differential waveform. | 45      | -       | 55      | %       |

Table 6. Electrical Characteristics – CMOS Outputs

| Symbol     | Parameter                       | Conditions   | Minimum                                      | Typical | Maximum                | Unit     |
|------------|---------------------------------|--|--|---------|------------------------|----------|
| $V_{OH}$   | Output High Voltage             | $I_{OH} = -15mA (3.3V), -12mA (2.5V), -8mA (1.8V).$<br>$V_{DDA}, V_{DDD}, V_{DDO0} = 3.3V$ and $2.5V$ .<br>$V_{DDA}, V_{DDD}, V_{DDO0} = 1.8V$ . | $0.7 \times V_{DDO}$<br>$0.5 \times V_{DDO}$ | -       | $V_{DDO}$<br>$V_{DDO}$ | V        |
| $V_{OL}$   | Output Low Voltage              | $I_{OL} = 15mA (3.3V), 12mA (2.5V), 8mA (1.8V)$ .  | -  | -       | 0.45                   | V        |
| $R_{OUT}$  | Output Driver Impedance         | CMOS output driver.  | -  | 17      | -                      | $\Omega$ |
| $T_{SR}$   | Slew Rate, SLEW[1:0] = 00       | Single-ended 3.3V LVC MOS output clock rise and fall time, 20% to 80% of $V_{DDO}$ (output load = 5pF) $V_{DDOX} = 3.3V$ .                       | 1.0  | 2.2     | -                      | V/ns     |
|            | Slew Rate, SLEW[1:0] = 01       |  | 1.2  | 2.3     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 10       |  | 1.3  | 2.4     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 11       |  | 1.7  | 2.7     | -                      |          |
| $T_{SR}$   | Slew Rate, SLEW[1:0] = 00       | Single-ended 2.5V LVC MOS output clock rise and fall time, 20% to 80% of $V_{DDO}$ (output load = 5pF) $V_{DDOX} = 2.5V$ .                       | 0.6  | 1.3     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 01       |  | 0.7  | 1.4     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 10       |  | 0.6  | 1.4     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 11       |  | 1.0  | 1.7     | -                      |          |
| $T_{SR}$   | Slew Rate, SLEW[1:0] = 00       | Single-ended 1.8V LVC MOS output clock rise and fall time, 20% to 80% of $V_{DDO}$ (output load = 5pF) $V_{DD} = 1.8V$ .                         | 0.3  | 0.7     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 01       |  | 0.4  | 0.8     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 10       |  | 0.4  | 0.9     | -                      |          |
|            | Slew Rate, SLEW[1:0] = 11       |  | 0.7  | 1.2     | -                      |          |
| $I_{OZDD}$ | Output Leakage Current (OUT1–4) | Tri-state outputs.   | -  | -       | 5                      | $\mu A$  |
|            | Output Leakage Current (OUT0)   | Tri-state outputs.   | -  | -       | 30                     | $\mu A$  |

**Table 7. Electrical Characteristics – LVDS Outputs**

| Symbol          | Parameter   | Minimum | Typical | Maximum | Unit |
|-----------------|---|---------|---------|---------|------|
| $V_{OT}(+)$     | Differential Output Voltage for the TRUE Binary State                           | 247     | -       | 454     | mV   |
| $V_{OT}(-)$     | Differential Output Voltage for the FALSE Binary State                          | -454    | -       | -247    | mV   |
| $\Delta V_{OT}$ | Change in $V_{OT}$ between Complementary Output States                          | -       | -       | 50      | mV   |
| $V_{OS}$        | Output Common Mode Voltage (Offset Voltage) at 3.3 V $\pm 5\%$ , 2.5V $\pm 5\%$ | 1.125   | 1.25    | 1.375   | V    |
|                 | Output Common Mode Voltage (Offset Voltage) at 1.8V $\pm 5\%$                   | 0.8     | 0.875   | 0.96    | V    |
| $\Delta V_{OS}$ | Change in $V_{OS}$ between Complementary Output States                          | -       | -       | 50      | mV   |
| $I_{OS}$        | Outputs Short Circuit Current, $V_{OUT}^+ = 0V$ or $V_{DDO}$                    | -       | 9       | 24      | mA   |
| $I_{OSD}$       | Differential Outputs Short Circuit Current, $V_{OUT}^+ = V_{OUT}^-$             | -       | 6       | 12      | mA   |
| $T_R$           | LVDS rise time 20%–80%  | -       | 300     | -       | ps   |
| $T_F$           | LVDS fall time 80%–20%  | -       | 300     | -       | ps   |

**Table 8. Electrical Characteristics – LVPECL Outputs**

| Symbol      | Parameter   | Minimum          | Typical | Maximum          | Unit |
|-------------|---|------------------|---------|------------------|------|
| $V_{OH}$    | Output Voltage High, Terminated through 50Ω tied to $V_{DD} - 2V$ | $V_{DDO} - 1.19$ | -       | $V_{DDO} - 0.69$ | V    |
| $V_{OL}$    | Output Voltage Low, Terminated through 50Ω tied to $V_{DD} - 2V$  | $V_{DDO} - 1.94$ | -       | $V_{DDO} - 1.4$  | V    |
| $V_{SWING}$ | Peak-to-Peak Output Voltage Swing                                 | 0.55             | -       | 0.993            | V    |
| $T_R$       | LVPECL rise time 20%–80%  | -                | 400     | -                | ps   |
| $T_F$       | LVPECL fall time 80%–20%  | -                | 400     | -                | ps   |

**Table 9. Electrical Characteristics – HCSL Outputs [1]**

| Symbol             | Parameter                  | Conditions   | Minimum | Typical | Maximum | Unit |
|--------------------|----------------------------|--|---------|---------|---------|------|
| $dV/dt$            | Slew Rate                  | Scope averaging on. [2][3]   | 1       | -       | 4       | V/ns |
| $\Delta dV/dt$     | Slew Rate Matching         | Scope averaging on. [3]  | -       | -       | 20      | %    |
| $V_{MAX}$          | Maximum Voltage            | Measurement on single-ended signal using absolute value (scope averaging off). | -       | -       | 1150    | mV   |
| $V_{MIN}$          | Minimum Voltage            |  | -300    | -       | -       | mV   |
| $V_{SWING}$        | Voltage Swing              | Scope averaging off. [2][4]  | 300     | -       | -       | mV   |
| $V_{CROSS}$        | Crossing Voltage Value     | Scope averaging off. [4][5]  | 250     | -       | 550     | mV   |
| $\Delta V_{CROSS}$ | Crossing Voltage Variation | Scope averaging off. [6]   | -       | -       | 140     | mV   |

1. Confirmed by design and characterization. Not 100% tested in production.
2. Measured from differential waveform.
3. Slew rate is measured through the  $V_{SWING}$  voltage range centered around differential 0V. This results in a  $\pm 150$ mV window around differential 0V.
4. Measured from single-ended waveform.
5.  $V_{CROSS}$  is defined as voltage where  $Clock = Clock\#$  measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).
6. The total variation of all  $V_{CROSS}$  measurements in any particular system. Note that this is a subset of  $V_{CROSS}$  min/max ( $V_{CROSS}$  absolute) allowed. The intent is to limit  $V_{CROSS}$  induced modulation by setting  $\Delta V_{CROSS}$  to be smaller than  $V_{CROSS}$  absolute.

Table 10. Spread Spectrum Generation Specifications

| Symbol       | Parameter        | Conditions   | Minimum | Typical                     | Maximum | Unit        |
|--------------|------------------|--|---------|-----------------------------|---------|-------------|
| $f_{SSOUT}$  | Spread Frequency | Output frequency range for spread spectrum.          | 5       | -                           | 300     | MHz         |
| $f_{MOD}$    | Mod Frequency    | Modulation frequency.                                |         | 30 to 63                    |         | kHz         |
| $f_{SPREAD}$ | Spread Value     | Amount of spread value (programmable)–center spread. |         | $\pm 0.25\%$ to $\pm 2.5\%$ |         | $\%f_{OUT}$ |
|              |                  | Amount of spread value (programmable)–down spread.   |         | -0.5% to -5%                |         |             |

## 4. I<sup>2</sup>C Bus Characteristics

Table 11. I<sup>2</sup>C Bus DC Characteristics(3.3V  $\pm 5\%$  only.)

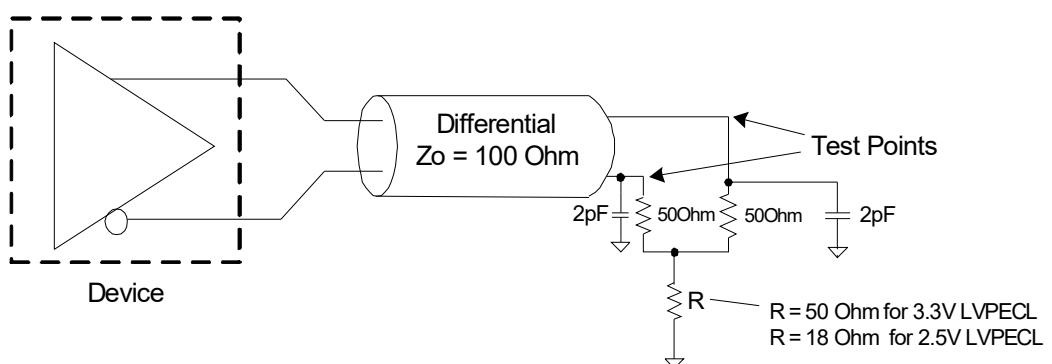
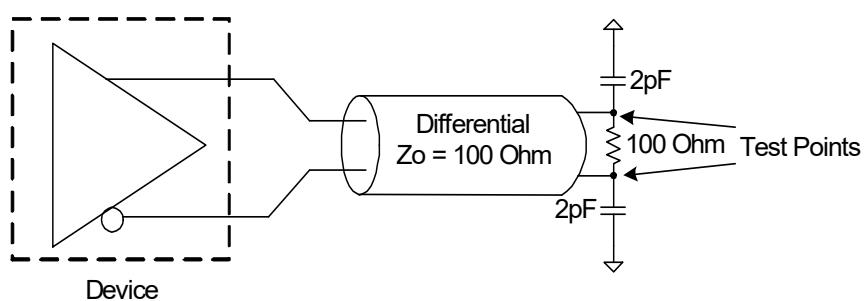
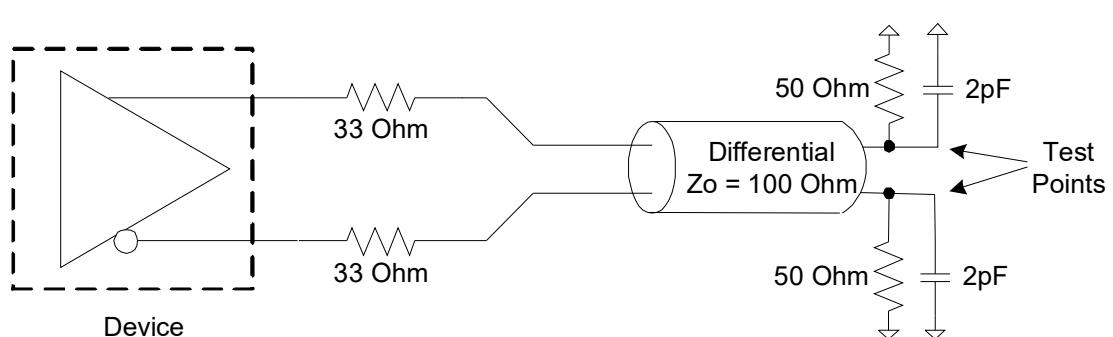
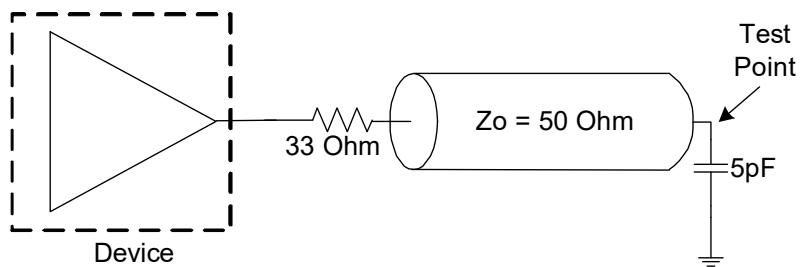
| Symbol    | Parameter             | Conditions                         | Minimum               | Typical | Maximum              | Unit    |
|-----------|-----------------------|------------------------------------|-----------------------|---------|----------------------|---------|
| $V_{IH}$  | Input High Level      | For SEL1/SDA pin and SEL0/SCL pin. | $0.7 \times V_{DDD}$  | -       | -                    | V       |
| $V_{IL}$  | Input Low Level       | For SEL1/SDA pin and SEL0/SCL pin. | -                     | -       | $0.3 \times V_{DDD}$ | V       |
| $V_{HYS}$ | Hysteresis of Inputs  | -                                  | $0.05 \times V_{DDD}$ | -       | -                    | V       |
| $I_{IN}$  | Input Leakage Current | -                                  | -                     | -       | 36                   | $\mu A$ |
| $V_{OL}$  | Output Low Voltage    | $I_{OL} = 3mA$ .                   | -                     | -       | 0.45                 | V       |

Table 12. I<sup>2</sup>C Bus AC Characteristics [1]

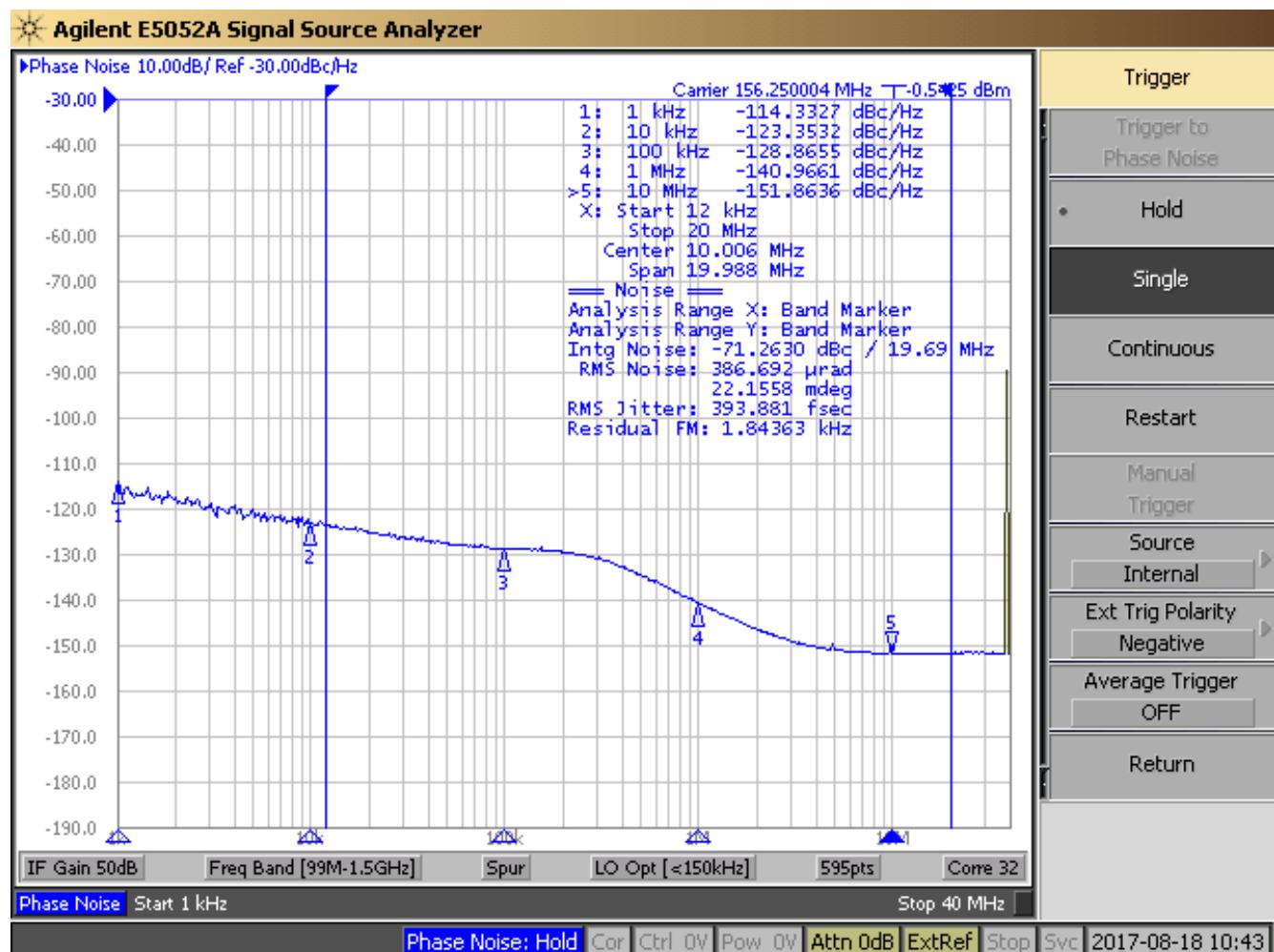
| Symbol         | Parameter                            | Conditions | Minimum               | Typical | Maximum | Unit    |
|----------------|--------------------------------------|------------|-----------------------|---------|---------|---------|
| $F_{SCLK}$     | Serial Clock Frequency (SCL)         | -          | 10                    | -       | 400     | kHz     |
| $t_{BUF}$      | Bus Free Time between Stop and Start | -          | 1.3                   | -       | -       | $\mu s$ |
| $t_{SU:START}$ | Setup Time, Start                    | -          | 0.6                   | -       | -       | $\mu s$ |
| $t_{HD:START}$ | Hold Time, Start                     | -          | 0.6                   | -       | -       | $\mu s$ |
| $t_{SU:DATA}$  | Setup Time, Data Input (SDA)         | -          | 0.1                   | -       | -       | $\mu s$ |
| $t_{HD:DATA}$  | Hold Time, Data Input (SDA) [2]      | -          | 0                     | -       | -       | $\mu s$ |
| $t_{OVD}$      | Output Data Valid from Clock         | -          | -                     | -       | 0.9     | $\mu s$ |
| $C_B$          | Capacitive Load for Each Bus Line    | -          | -                     | -       | 400     | pF      |
| $t_R$          | Rise Time, Data and Clock (SDA, SCL) | -          | $20 + 0.1 \times C_B$ | -       | 300     | ns      |
| $t_F$          | Fall Time, Data and Clock (SDA, SCL) | -          | $20 + 0.1 \times C_B$ | -       | 300     | ns      |
| $t_{HIGH}$     | High Time, Clock (SCL)               | -          | 0.6                   | -       | -       | $\mu s$ |
| $t_{LOW}$      | Low Time, Clock (SCL)                | -          | 1.3                   | -       | -       | $\mu s$ |
| $t_{SU:STOP}$  | Setup Time, Stop                     | -          | 0.6                   | -       | -       | $\mu s$ |

1. I<sup>2</sup>C inputs are 5V tolerant.
2. A device must internally provide a hold time of at least 300ns for the SDA signal (referred to the  $V_{IH(MIN)}$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.

## 5. Test Loads



## 6. Jitter Performance Characteristics



Note: Measured with OUT2 = 156.25MHz on, 39.625MHz input.

Table 13. Jitter Performance [1][2]

| Symbol      | Parameter                      | Conditions  | Minimum | Typical | Maximum | Unit |
|-------------|--------------------------------|---|---------|---------|---------|------|
| $J_{CY-CY}$ | Cycle to Cycle Jitter          | LVCMOS 3.3V $\pm 5\%$ , -40°C–90°C.                   | -       | 5       | 30      | ps   |
|             |                                | All differential outputs 3.3V $\pm 5\%$ , -40°C–90°C. | -       | 25      | 35      | ps   |
| $J_{PK-PK}$ | Period Jitter                  | LVCMOS 3.3V $\pm 5\%$ , -40°C–90°C.                   | -       | 28      | 40      | ps   |
|             |                                | All differential outputs 3.3V $\pm 5\%$ , -40°C–90°C. | -       | 4       | 30      | ps   |
| $J_{RMS}$   | RMS Phase Jitter (12kHz–20MHz) | LVCMOS 3.3V $\pm 5\%$ , -40°C–90°C.                   | -       | 0.3     | -       | ps   |
|             |                                | All differential outputs 3.3V $\pm 5\%$ , -40°C–90°C. | -       | 0.5     | -       | ps   |

1. Measured with 25MHz crystal input.

2. Configured with OUT0 = 25MHz–LVCMOS; OUT1 = 100MHz–HCSL; OUT2 = 125MHz–LVDS; OUT3 = 156.25MHz–LVPECL.

## 6.1 PCI Express Jitter Performance and Specifications

Table 14. PCI Express Jitter Performance [1][2]

| Parameter                     | Symbol               | Conditions  | Minimum | Typical | Maximum | Industry Limits | Unit     |
|-------------------------------|----------------------|---|---------|---------|---------|-----------------|----------|
| PCIe Jitter (Common Clock-CC) | $t_{jphPCleG1-CC}$   | PCIe Gen1 [3]   | -       | 28.7    | -       | 86              | ps (p-p) |
|                               | $t_{jphPCleG2-CC}$   | PCIe Gen2 Low Band<br>10kHz < f < 1.5MHz<br>(PLL BW of 5–16MHz or 8–16MHz, CDR = 5MHz).           | -       | 0.27    | -       | 3               | ps (rms) |
|                               |                      | PCIe Gen High Band<br>1.5MHz < f < Nyquist (50MHz)<br>(PLL BW of 5–16MHz or 8–16MHz, CDR = 5MHz). | -       | 2.56    | -       | 3.1             | ps (rms) |
|                               | $t_{jphPCleG3-CC}$   | PCIe Gen3<br>(PLL BW of 2–4MHz or 2–5MHz, CDR = 10MHz).   | -       | 0.8     | -       | 1               | ps (rms) |
|                               | $t_{jphPCleG4-CC}$   | PCIe Gen4<br>(PLL BW of 2–4MHz or 2–5MHz, CDR = 10MHz).   | -       | 0.26    | -       | 0.5             | ps (rms) |
| PCIe Jitter (IR) [4][5]       | $t_{jphPCleG2-SRIS}$ | PCIe Gen2 (SSC off)<br>(PLL BW of 16MHz, CDR = 5MHz).   | -       | 0.93    | -       | 2               | ps (rms) |
|                               | $t_{jphPCleG3-SRIS}$ | PCIe Gen3 (SSC off)<br>(PLL BW of 2–4MHz or 2–5MHz, CDR = 10MHz).                                 | -       | 0.32    | -       | 0.7             | ps (rms) |

1. Confirmed by design and characterization, not 100% tested in production.
2. Based on PCIe Base Specification Rev 4.0 version 1.0. See <http://www.pcisig.com> for latest specifications.
3. Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1<sup>-12</sup>.
4. According to the PCIe Base Specification Rev4.0 version 1.0, the jitter transfer functions and corresponding jitter limits are not defined for the IR clock architecture. Widely accepted industry limits using widely accepted industry filters are used to populate this table. There are no accepted filters or limits for IR clock architectures at PCIe Gen1 or Gen4 data rates.
5. IR (Independent Reference) is the new name for Separate Reference Independent Spread (SRIS) and Separate Reference no Spread (SRNS) PCIe clock architectures.

## 7. Features and Functional Blocks

### 7.1 Device Startup and Power-On-Reset

The device has an internal power-up reset (POR) circuit. All  $V_{DD}$ s must be connected to desired supply voltage to trigger POR.

User can define specific default configurations through internal One-Time-Programmable (OTP) memory. Either customer or factory can program the default configuration. Please refer to [VersaClock 6E Family Register Descriptions and Programming Guide](#) for details or contact Renesas if a specific factory-programmed default configuration is required.

Device will identify which of the 2 modes to operate in by the state of OUT0\_SEL\_I2CB pin at POR. Both of the modes default configurations can be programmed as stated above.

1. **Software Mode (I<sup>2</sup>C):** OUT0\_SEL\_I2CB is low at POR.

I<sup>2</sup>C interface will be open to users for in-system programming, overriding device default configurations at any time.

2. **Hardware Select Mode:** OUT0\_SEL\_I2CB is high at POR.

Device has been programmed to load OTP at power-up (REG0[7] = 1). The device will load internal registers according to [Table 15](#).

Internal OTP memory can support up to 4 configurations, selectable by SEL0/SEL1 pins.

At POR, logic levels at SEL0 and SEL1 pins must be settled, resulting the selected configuration to be loaded at power up.

After the first 10ms of operation, the levels of the SELx pins can be changed, either to low or to the same level as V<sub>DDD</sub>/V<sub>DDA</sub>. The SELx pins must be driven with a digital signal of < 300ns rise/fall time and only a single pin can be changed at a time. After a pin level change, the device must not be interrupted for at least 1ms so that the new values have time to load and take effect.

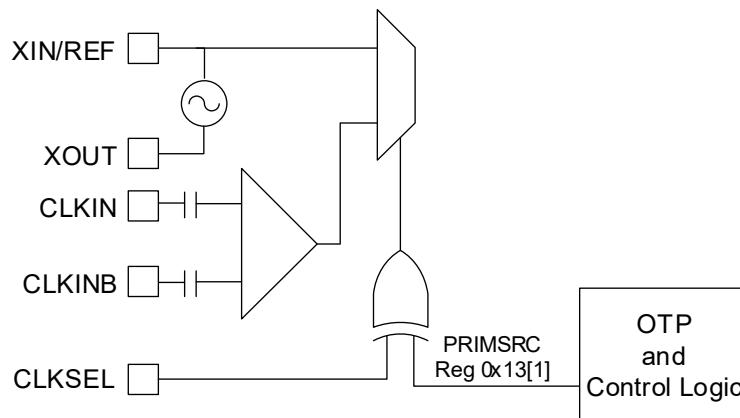
**Table 15. Power-up Behavior**

| OUT0_SEL_I2CB at POR | SEL1 | SEL0 | I <sup>2</sup> C Access | REG0:7 | Config                    |
|----------------------|------|------|-------------------------|--------|---------------------------|
| 1                    | 0    | 0    | No                      | 0      | 0                         |
| 1                    | 0    | 1    | No                      | 0      | 1                         |
| 1                    | 1    | 0    | No                      | 0      | 2                         |
| 1                    | 1    | 1    | No                      | 0      | 3                         |
| 0                    | X    | X    | Yes                     | 1      | I <sup>2</sup> C defaults |
| 0                    | X    | X    | Yes                     | 0      | 0                         |

## 7.2 Reference Clock and Selection

The device supports up to two clock inputs.

- Crystal input, can be driven by a single-ended clock.
- Clock input (CLKIN, CLKINB), a fully differential input that only accepts a reference clock. A single-ended clock can also drive it on CLKIN.



**Figure 6. Clock Input Diagram, Internal Logic**

## 7.3 Manual Switchover

The CLKSEL pin selects the input clock between either XTAL/REF or (CLKIN, CLKINB). CLKSEL polarity can be changed by I<sup>2</sup>C programming (Byte 0x13[1]) as shown in [Table 16](#).

0 = XIN/REF, XOUT (default); 1 = CLKIN, CLKINB.

Table 16. Input Clock Select

| PRIMSRC<br>(Register 0x13[1]) | CLKSEL | Source        |
|-------------------------------|--------|---------------|
| 0                             | 0      | XIN/REF       |
| 0                             | 1      | CLKIN, CLKINB |
| 1                             | 0      | CLKIN, CLKINB |
| 1                             | 1      | XIN/REF       |

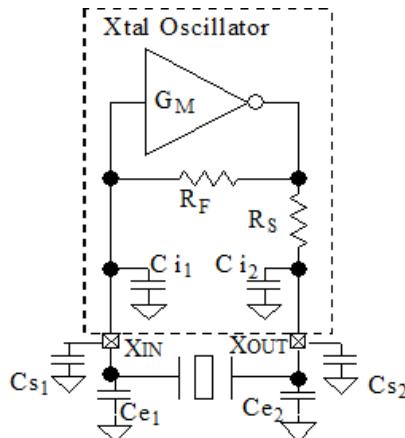
When SM[1:0] is “0x”, the redundant inputs are in manual switchover mode. In this mode, CLKSEL pin is used to switch between the primary and secondary clock sources. The PRIMSRC bit determines the primary and secondary clock source setting. During the switchover, no glitches will occur at the output of the device, although there may be frequency and phase drift, depending on the exact phase and frequency relationship between the primary and secondary clocks.

## 7.4 Internal Crystal Oscillator (XIN/REF)

### 7.4.1 Choosing Crystals

A crystal manufacturer will calibrate its crystals to the nominal frequency with a certain load capacitance value. When the oscillator load capacitance matches the crystal load capacitance, the oscillation frequency will be accurate. When the oscillator load capacitance is lower than the crystal load capacitance, the oscillation frequency will be higher than nominal and vice versa so for an accurate oscillation frequency you need to make sure to match the oscillator load capacitance with the crystal load capacitance.

### 7.4.2 Tuning the Crystal Load Capacitor



Cs1 and Cs2 are stray capacitances at each crystal pin and typical values are between 1pF and 3pF.

Ce1 and Ce2 are additional external capacitors, increasing the load capacitance reduces the oscillator gain so please consult the factory when adding Ce1 and/or Ce2 to avoid crystal startup issues. Ci1 and Ci2 are integrated programmable load capacitors, one at XIN and one at XOUT. Ci1 and Ci2.

The value of each capacitor is composed of a fixed capacitance amount plus a variable capacitance amount set with the XTAL[5:0] register.

Ci1 and Ci2 are commonly programmed to be the same value. Adjustment of the crystal tuning capacitors allows maximum flexibility to accommodate crystals from various manufacturers. The range of tuning capacitor values available are in accordance with the following table.

Ci1/Ci2 starts at 9pF with setting 000000b and can be increased up to 25pF with setting 111111b. The step per bit is 0.5pF.

Table 17. XTAL[5:0] Tuning Capacitor

| Parameter | Bits | Step (pF) | Minimum (pF) | Maximum (pF) |
|-----------|------|-----------|--------------|--------------|
| XTAL      | 6    | 0.5       | 9            | 25           |

You can write the following equation for this capacitance:

$$C_i = 9pF + 0.5pF \times XTAL[5:0]$$

$$C_{XIN} = Ci1 + Cs1 + Ce1$$

$$C_{XOUT} = Ci2 + Cs2 + Ce2$$

The final load capacitance of the crystal:

$$C_L = C_{XIN} \times C_{XOUT} / (C_{XIN} + C_{XOUT})$$

It is recommended to set the same value for capacitors the same at each crystal pin, meaning:

$$C_{XIN} = C_{XOUT}$$

**Example 1:** The crystal load capacitance is specified as 8pF and the stray capacitance at each crystal pin is Cs = 1.5pF. Assuming equal capacitance value at XIN and XOUT, the equation is as follows:

$$8pF = (9pF + 0.5pF \times XTAL[5:0] + 1.5pF) / 2$$

$$\text{So, } XTAL[5:0] = 11 \text{ (decimal).}$$

**Example 2:** The crystal load capacitance is specified as 12pF and the stray capacitance Cs is unknown.

Footprints for external capacitors Ce are added and a worst case Cs of 5pF is used. For now we use Cs + Ce = 5pF and the right value for Ce can be determined later to make 5pF together with Cs.

$$12pF = (9pF + 0.5pF \times XTAL[5:0] + 5pF) / 2$$

$$\text{So, } XTAL[5:0] = 20 \text{ (decimal).}$$

Table 18. Recommended Crystal Characteristics

| Parameter                                     | Minimum     | Typical | Maximum | Unit     |
|---|-------------|---------|---------|----------|
| Mode of Oscillation                           | Fundamental |         |         |          |
| Frequency                                     | 8           | 25      | 40      | MHz      |
| Equivalent Series Resistance (ESR)            |             | 10      | 100     | $\Omega$ |
| Shunt Capacitance                             |             |         | 7       | pF       |
| Load Capacitance ( $C_L$ ) at $<= 25MHz$      | 6           | 8       | 12      | pF       |
| Load Capacitance ( $C_L$ ) $> 25MHz$ to 40MHz | 6           |         | 8       | pF       |
| Maximum Crystal Drive Level                   |             |         | 100     | $\mu W$  |

## 7.5 Programmable Loop Filter

Table 19. Loop Filter

The device PLL loop bandwidth range depends on the input reference frequency (Fref).

| Input Reference Frequency (MHz) | Loop Bandwidth Minimum (kHz) | Loop Bandwidth Maximum (kHz) |
|---------------------------------|------------------------------|------------------------------|
| 1                               | 40                           | 126                          |
| 350                             | 300                          | 1000                         |

## 7.6 Fractional Output Dividers (FOD)

The device has 4 fractional output dividers (FOD). Each of the FODs are comprised of a 12-bit integer counter, and a 24-bit fractional counter. The output divider can operate in integer divide only mode for improved performance, or utilize the fractional counters to generate a clock frequency accurate to 50ppb.

FOD has the following features:

### 7.6.1 Individual Spread Spectrum Modulation

The output clock frequencies can be modulated to spread energy across a broader range of frequencies, lowering system EMI.

Each divider has individual spread ability. Spread modulation independent of output frequency, a triangle wave modulation between 30kHz and 63kHz.

Spread spectrum can be applied to any output clock, any clock frequency, and any spread amount from  $\pm 0.25\%$  to  $\pm 2.5\%$  center-spread and -0.5% to -5% down-spread.

### 7.6.2 Bypass Mode

Bypass mode (divide by 1) to allow the output to behave as a buffered copy from the input or another FOD.

### 7.6.3 Dividers Alignment

Each output divider block has a synchronizing pulse to provide startup alignment between outputs dividers. This allows alignment of outputs for low skew performance.

When the device is at hardware select mode, outputs will be automatically aligned at POR. The same synchronization reset is also triggered when switching between configurations with the SEL0/1 pins. This ensures that the outputs remain aligned in every configuration.

When using software mode I<sup>2</sup>C to reprogram an output divider during operation, alignment can be lost. Alignment can be restored by manually triggering the reset through I<sup>2</sup>C.

The outputs are aligned on the falling edges of each output by default. Rising edge alignment can also be achieved by utilizing the programmable skew feature to delay the faster clock by 180 degrees. The programmable skew feature also allows for fine tuning of the alignment.

### 7.6.4 Programmable Skew

The device has the ability to skew outputs by quadrature values. The skew on each output can be adjusted from 0 to 360 degrees. Skew is adjusted in units equal to 1/32 of the VCO period. So, for 100MHz output and a 2500MHz VCO, you can select how many 12.5ps units you want added to your skew (resulting in units of 0.45 degrees). For example, 0, 0.45, 0.90, 1.35, 1.80, and so on. The granularity of the skew adjustment is always dependent on the VCO period and the output period.

## 7.7 Output Drivers

The device output drivers support the following features individually:

- 2.5V or 3.3V voltage level for HCSL/LVPECL operation
- 1.8V, 2.5V or 3.3V voltage levels for CMOS/LVDS operation
- CMOS supports 4 operating modes:
  - CMOSD: OUTx and OUTxB 180 degrees out of phase
  - CMOSX2: OUTx and OUTxB phase-aligned
  - CMOS1: only OUTx pin is on
  - CMOS2: only OUTxB pin is on

When a given output is configured to at CMOSD or CMOSX2, then all previously described configuration and control apply equally to both pins.

- Independent output enable/disabled by register bits. When disabled, an output can be either in a logic 1 state or Hi-Z.

The following options are used to disable outputs:

1. Output turned off by I<sup>2</sup>C.
2. Output turned off by SD/OE pin.
3. Output unused, which means is turned off regardless of OE pin status.

## 7.8 SD/OE Pin Function

SD/OE pin can be programmed as following functions:

1. OE output enable (low active).
2. OE output enable (high active).
  - a. *Note:* In this mode, toggling the OE input from low level to high level is mandatory to activate outputs. This should occur after the device has started up and the PLL has reached lock status. Please refer to [VersaClock 6E Family Register Descriptions and Programming Guide](#), chapter "Shutdown Function", for details.
3. Global shutdown (low active).
4. Global shutdown (high active).

Output behavior when disabled is also programmable. User will have the option to choose output driver behavior when it's off:

1. OUTx pin high, OUTxB pin low. (Controlled by SD/OE pin).
2. OUTx/OUTxB Hi-Z (Controlled by SD/OE pin).
3. OUTx pin high, OUTxB pin low. (Configured through I<sup>2</sup>C).
4. OUTx/OUTxB Hi-Z (Configured by I<sup>2</sup>C).

The user has the option to disable the output with either I<sup>2</sup>C or SD/OE pin. Refer to [VersaClock 6E Family Register Descriptions and Programming Guide](#) for details.

## 7.9 I<sup>2</sup>C Operation

The device acts as a slave device on the I<sup>2</sup>C bus using one of the two I<sup>2</sup>C addresses (0xD0 or 0xD4) to allow multiple devices to be used in the system. The interface accepts byte-oriented block write and block read operations.

Address bytes (2 bytes) specify the register address of the byte position of the first register to write or read.

Data bytes (registers) are accessed in sequential order from the lowest to the highest byte (most significant bit first).

Read and write block transfers can be stopped after any complete byte transfer. During a write operation, data will not be moved into the registers until the STOP bit is received, at which point, all data received in the block write will be written simultaneously.

For full electrical I<sup>2</sup>C compliance, use external pull-up resistors for SDATA and SCLK.

Current Read



Sequential Read



Sequential Write



from master to slave

S = start

from slave to master

Sr = repeated start

A = acknowledge

Abar= none acknowledge

P = stop

Figure 7. I<sup>2</sup>C R/W Sequence

## 8. Typical Application Circuit

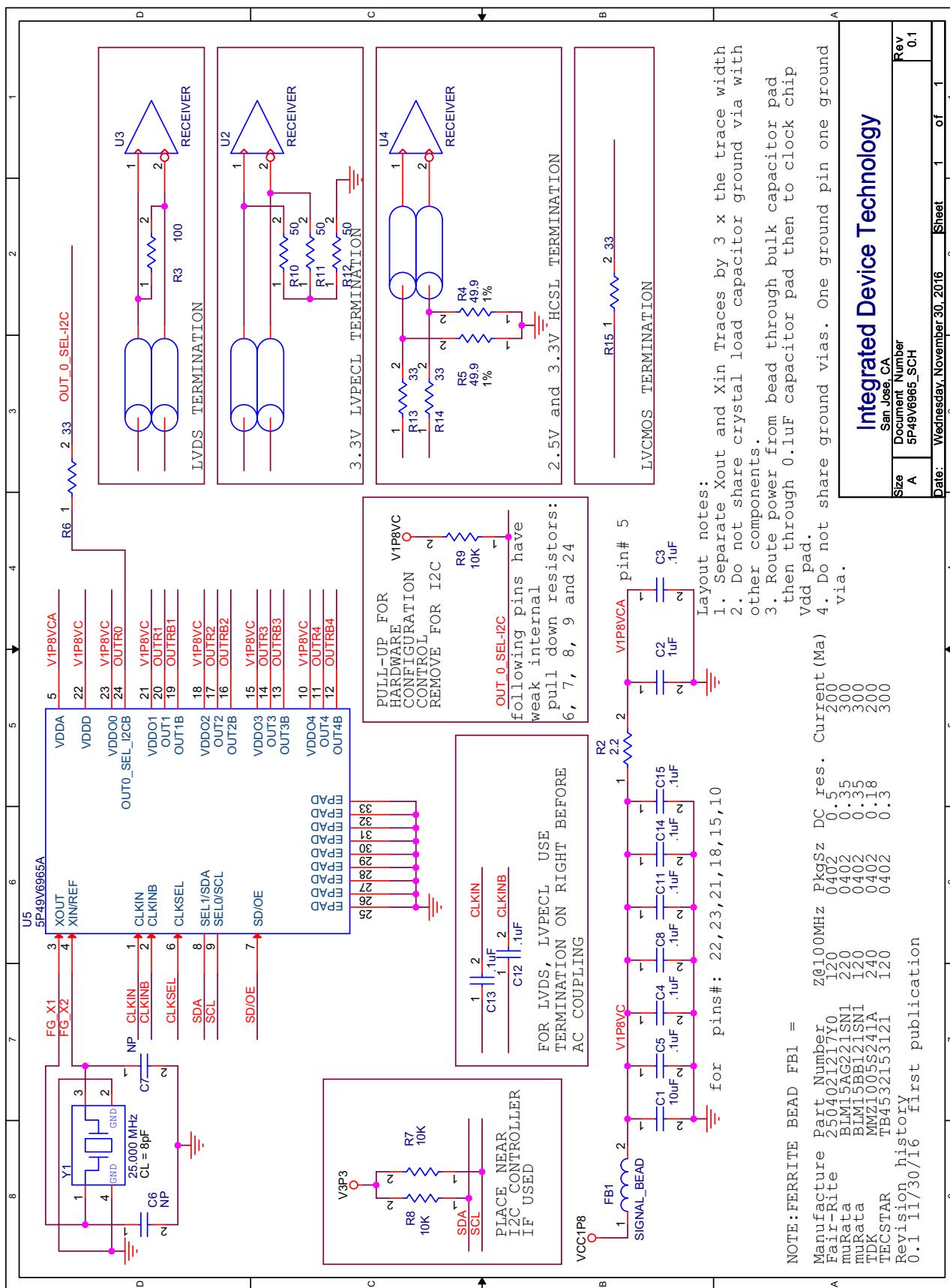


Figure 8. Application Circuit Example

## 8.1 Input – Driving the XIN/REF or CLKIN

### 8.1.1 Driving XIN/REF with a CMOS Driver

In some cases, it is encouraged to have XIN/REF driven by a clock input for reasons like better SNR, multiple input select with device CLKIN, etc. The XIN/REF pin requires an input amplitude between 500mV and 1.2V. The clock slew rate should be at least 0.2V/ns ( $\geq 0.2V/ns$ ).

The XIN/REF input can be overdriven by an LVCMS driver or by one side of a differential driver through an AC coupling capacitor. The XOUT pin can be left floating.

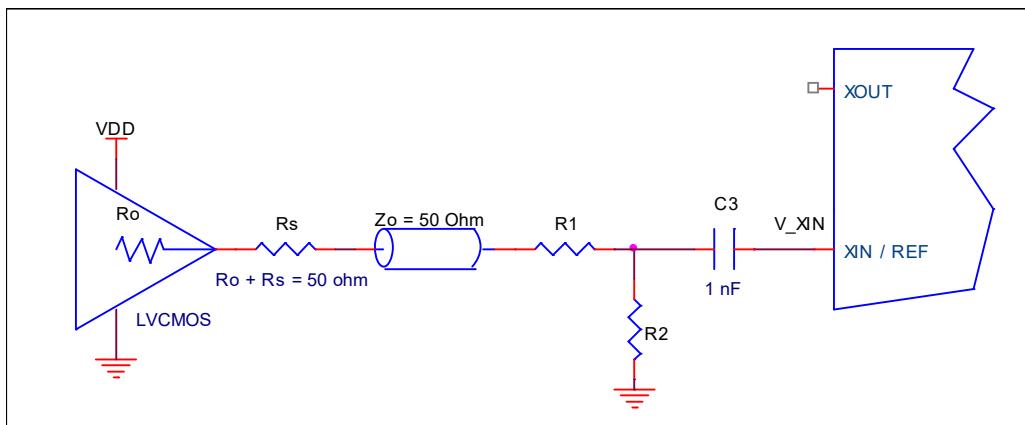


Figure 9. Overdriving XIN with a CMOS Driver

Table 20. Nominal Voltage Divider Values for Overdriving XIN with Single-ended Driver

| LVCMS Diver $V_{DD}$ | $Ro + Rs$ | $R1$ | $R2$ | $V_{XIN}$ (peak) | $Ro + Rs + R1 + R2$ |
|----------------------|-----------|------|------|------------------|---------------------|
| 3.3                  | 50.0      | 130  | 75   | 0.97             | 255                 |
| 2.5                  | 50.0      | 100  | 100  | 1.00             | 250                 |
| 1.8                  | 50.0      | 62   | 130  | 0.97             | 242                 |

### 8.1.2 Driving XIN with an LVPECL Driver

Figure 10 shows an example of the interface diagram for a +3.3V LVPECL driver. This is a standard LVPECL termination with one side of the driver feeding the XIN/REF input. It is recommended that all components in the schematics be placed in the layout; though some components might not be used, they can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a quartz crystal as the input. If the driver is 2.5V LVPECL, the only change necessary is to use the appropriate value of R3.

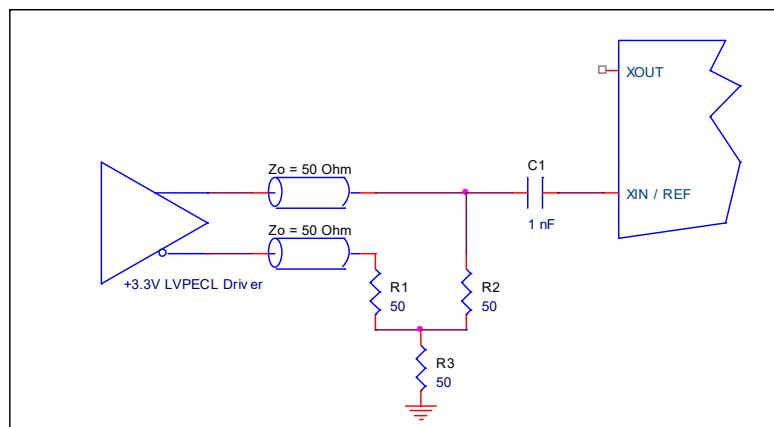


Figure 10. Overdriving XIN with an LVPECL Driver

### 8.1.3 Wiring the CLKIN Pin to Accept Single-ended Inputs

CLKIN cannot take a signal larger than 1.2V pk-pk due to the 1.2V regulated input inside. However, it is internally AC coupled so it is able to accept both LVDS and LVPECL input signals.

Occasionally, it is desired to have CLKIN to take CMOS levels. Below is an example showing how this can be achieved.

This configuration has three properties:

1. Total output impedance of  $R_o$  and  $R_s$  matches the  $50\Omega$  transmission line impedance.
2.  $V_{rx}$  voltage is generated at the CLKIN which maintains the LVCMOS driver voltage level across the transmission line for best S/N.
3.  $R_1$ - $R_2$  voltage divider values ensure that  $V_{rx}$  p-p at CLKIN is less than the maximum value of 1.2V.

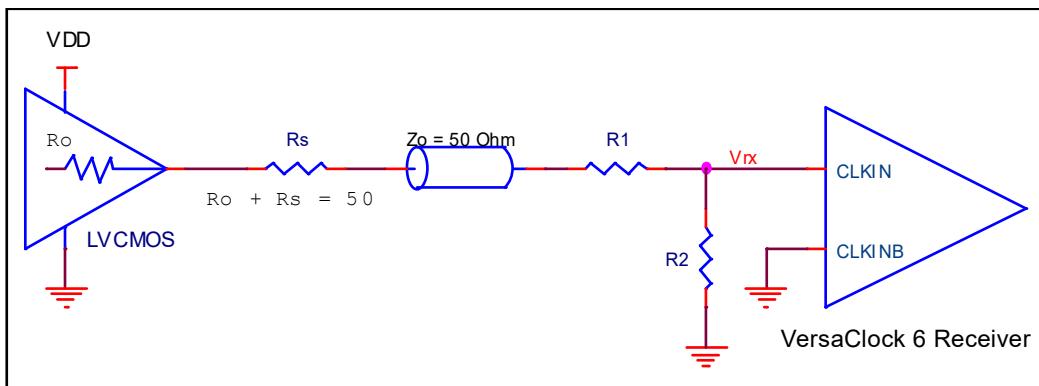


Figure 11. Recommended Schematic for Driving CLKIN with LVCMOS Driver

Table 21 shows resistor values that ensure the maximum drive level for the CLKIN port is not exceeded for all combinations of 5% tolerance on the driver  $V_{DD}$ ,  $V_{DD00}$  and 5% resistor tolerances. The values of the resistors can be adjusted to reduce the loading for slower and weaker LVCMOS driver by increasing the impedance of the  $R_1$ - $R_2$  divider. To better assist this assessment, the total load ( $R_o + R_s + R_1 + R_2$ ) on the driver is included in the table.

Table 21. Nominal Voltage Divider Values for Overdriving CLKIN with Single-ended Driver

| LVCMOS Diver $V_{DD}$ | $R_o + R_s$ | $R_1$ | $R_2$ | $V_{rx}$ (peak) | $R_o + R_s + R_1 + R_2$ |
|-----------------------|-------------|-------|-------|-----------------|-------------------------|
| 3.3                   | 50.0        | 130   | 75    | 0.97            | 255                     |
| 2.5                   | 50.0        | 100   | 100   | 1.00            | 250                     |
| 1.8                   | 50.0        | 62    | 130   | 0.97            | 242                     |

### 8.1.4 Driving CLKIN with Differential Clock

CLKIN/CLKINB will accept DC coupled HCSL/LVPECL/LVDS signals.

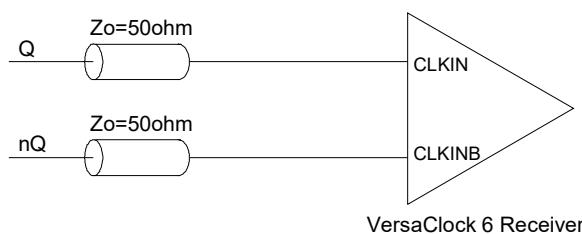


Figure 12. CLKIN, CLKINB Input Driven by an HCSL Driver

## 8.2 Output – Single-ended or Differential Clock Terminations

### 8.2.1 LVDS Termination

For a general LVDS interface, the recommended value for the termination impedance ( $Z_T$ ) is between  $90\Omega$  and  $132\Omega$ . The actual value should be selected to match the differential impedance ( $Z_0$ ) of your transmission line. A typical point-to-point LVDS design uses a  $100\Omega$  parallel resistor at the receiver and a  $100\Omega$  differential transmission-line environment. In order to avoid any transmission-line reflection issues, the components should be surface mounted and must be placed as close to the receiver as possible. The standard termination schematic as shown in figure “Standard Termination” or the termination of figure “Optional Termination” can be used, which uses a center tap capacitance to help filter common mode noise. The capacitor value should be approximately  $50\text{pF}$ . In addition, since these outputs are LVDS compatible, the input receiver's amplitude and common-mode input range should be verified for compatibility with the Renesas LVDS output. If using a non-standard termination, it is recommended to contact Renesas and confirm that the termination will function as intended. For example, the LVDS outputs cannot be AC coupled by placing capacitors between the LVDS outputs and the  $100\Omega$  shunt load. If AC coupling is required, the coupling caps must be placed between the  $100\Omega$  shunt termination and the receiver. In this manner, the termination of the LVDS output remains DC coupled.

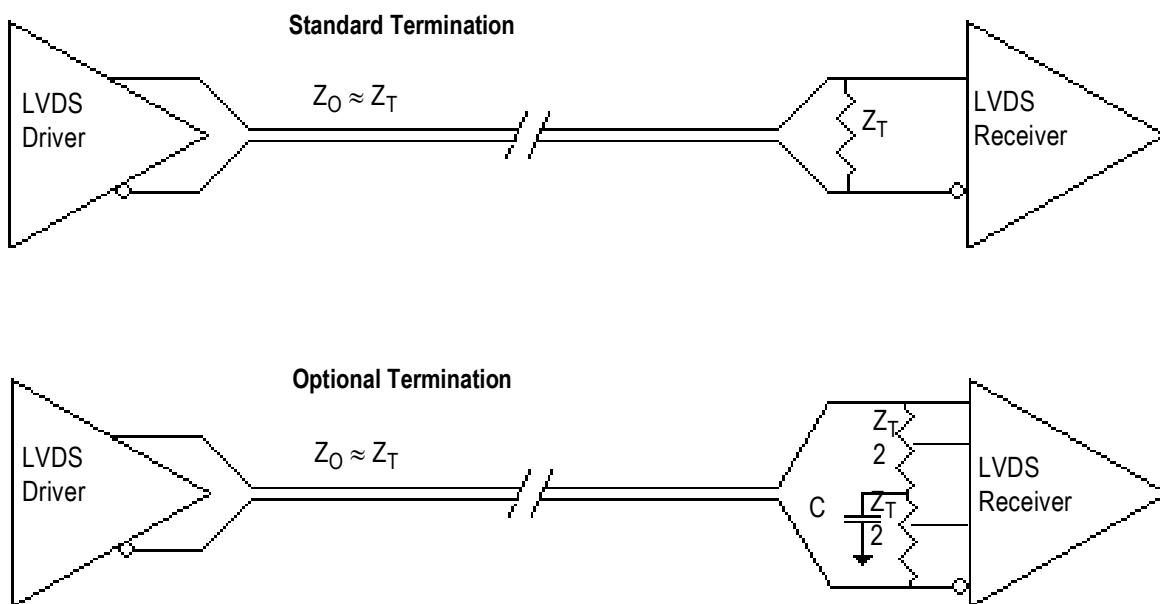


Figure 13. Standard and Optional Terminations

### 8.2.2 LVPECL Termination

The clock layout topology shown below is a typical termination for LVPECL outputs.

The differential outputs generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive  $50\Omega$  transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion.

For  $V_{DDO} = 2.5\text{V}$ , the  $V_{DDO} - 2\text{V}$  is very close to ground level. The R3 in 2.5V LVPECL output termination can be eliminated and the termination is shown in [Figure 16](#), 2.5V LVPECL Output Termination.

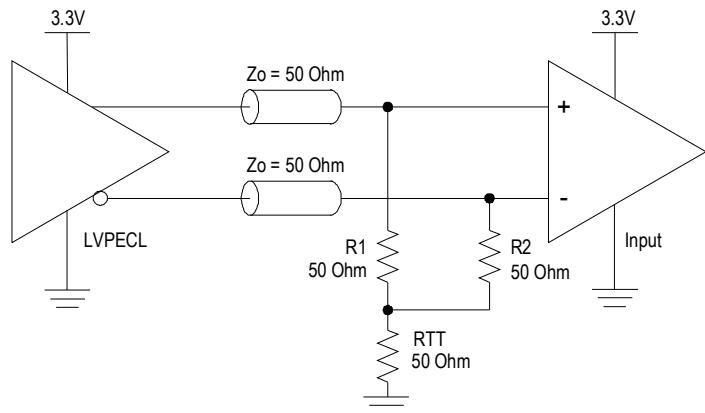


Figure 14. 3.3V LVPECL Output Termination (1)

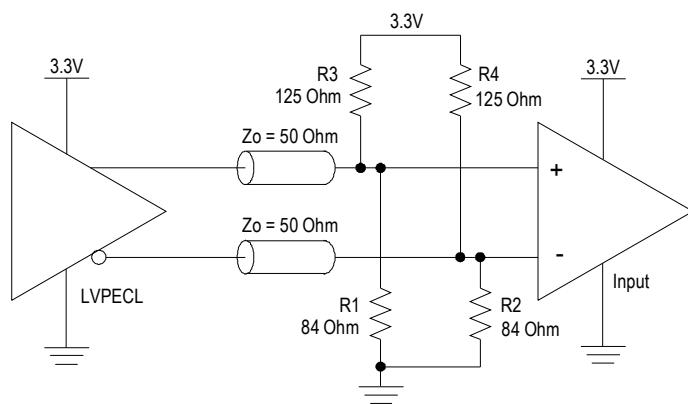


Figure 15. 3.3V LVPECL Output Termination (2)

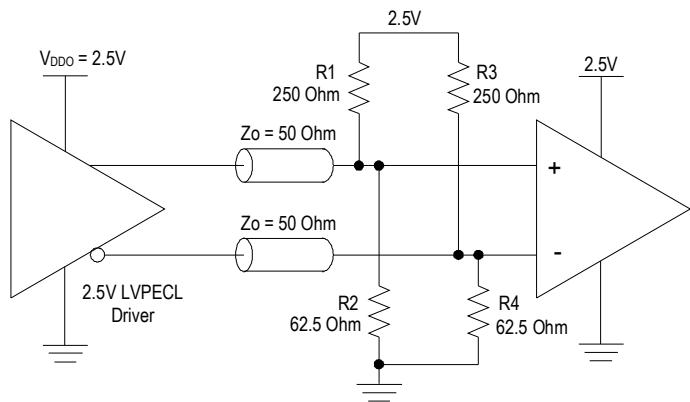


Figure 16. 2.5V LVPECL Output Termination

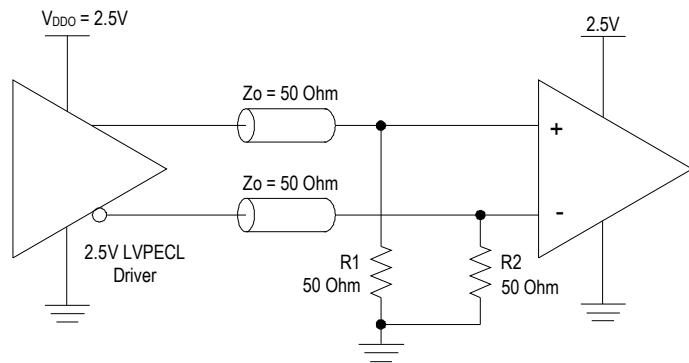


Figure 17. 2.5V LVPECL Driver Termination (1)

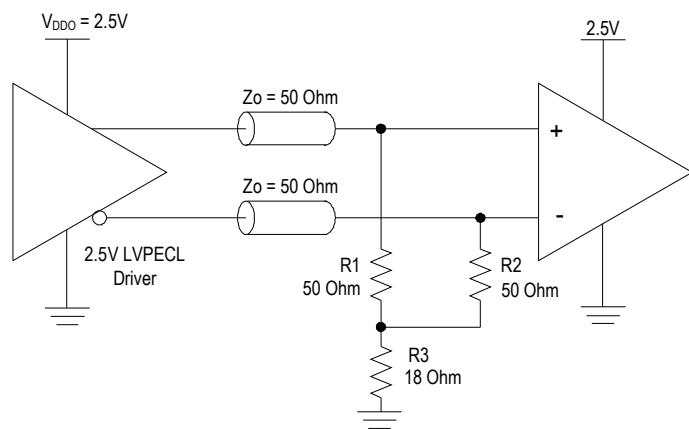


Figure 18. 2.5V LVPECL Driver Termination (2)

### 8.2.3 HCSL Termination

HCSL termination scheme applies to both 3.3V and 2.5V  $V_{DDO}$ .

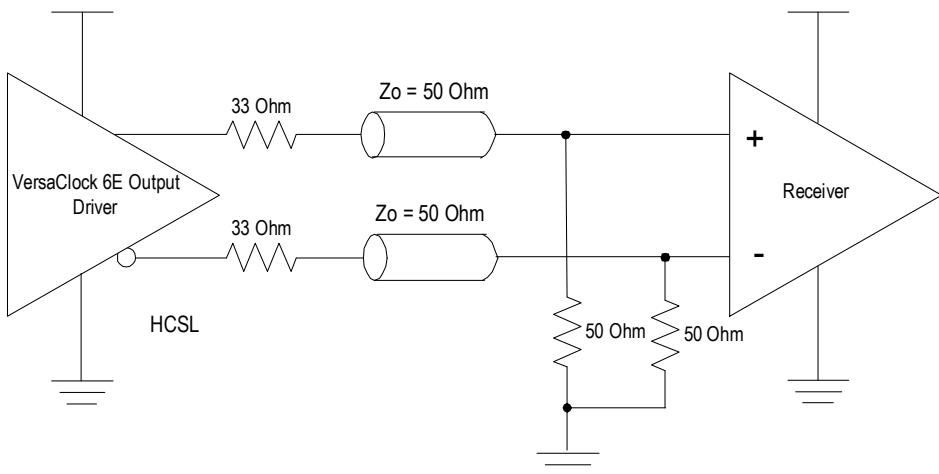


Figure 19. HCSL Receiver Terminated

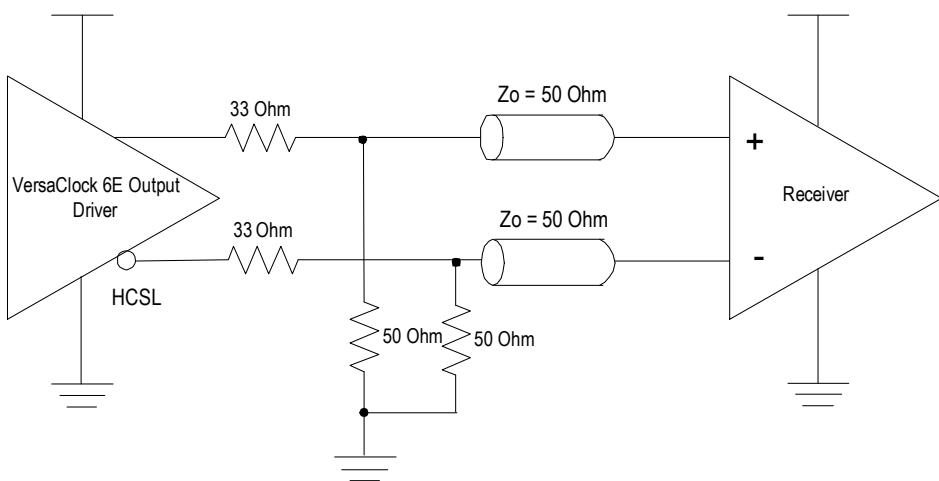


Figure 20. HCSL Source Terminated

### 8.2.4 LVC MOS Termination

Each output pair can be configured as a standalone CMOS or dual-CMOS output driver. Example of CMOSD driver termination is shown below.

CMOS1 – Single CMOS active on OUTx pin.

CMOS2 – Single CMOS active on OUTxB pin.

CMOSD – Dual CMOS outputs active on both OUTx and OUTxB pins, 180 degrees out of phase.

CMOSX2 – Dual CMOS outputs active on both OUTx and OUTxB pins, in-phase.

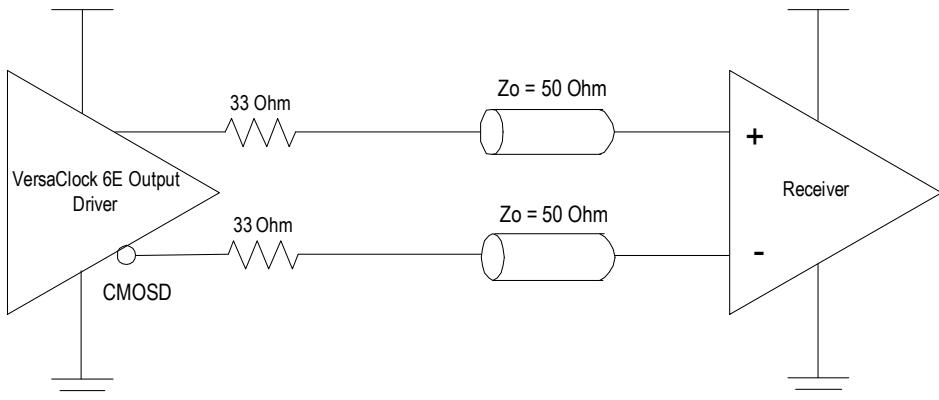
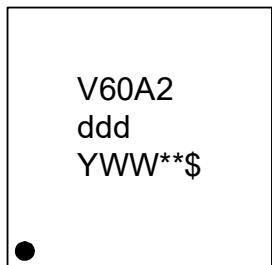


Figure 21. LVC MOS Termination

## 9. Package Outline Drawings

The package outline drawings are located at the end of this document and are accessible from the Renesas website (see [Ordering Information](#) for POD links). The package information is the most current data available and is subject to change without revision of this document.

## 10. Marking Diagram



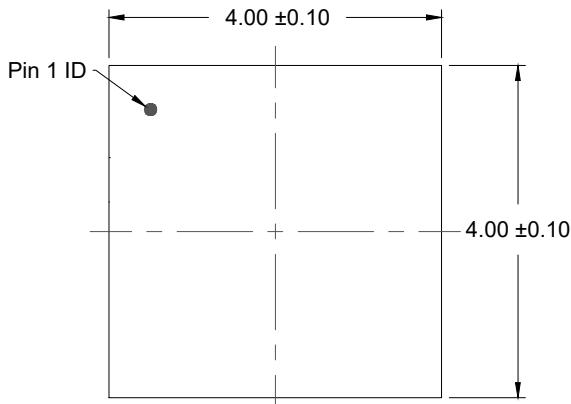
- Line 1: truncated part number.
- Line 2: “ddd” denotes dash code.
- Line 3:
  - “YWW” is the last digit of the year and week that the part was assembled.
  - “\*\*” denotes sequential lot number.
  - “\$” denotes mark code.

## 11. Ordering Information

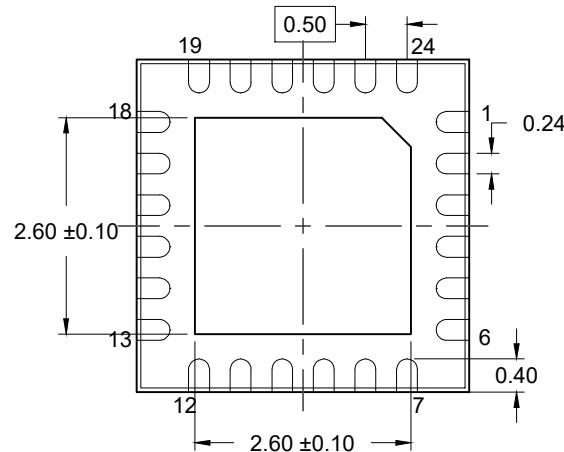
| Part Number      | Package Description                                 | Carrier Type | Temperature Range |
|------------------|---|--------------|-------------------|
| 5P49V60AdddNLG2  | 24-VFQFPN, 4 × 4 mm,<br>0.5mm pitch, wettable flank | Tray         | -40 to +105°C     |
| 5P49V60AdddNLG28 |   | Reel         |                   |

## 12. Revision History

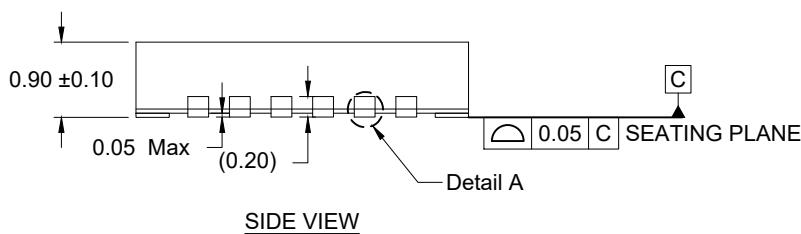
| Revision | Date         | Description  |
|----------|--------------|--|
| 1.10     | Dec 16, 2022 | <ul style="list-style-type: none"> <li>Changed first line of Description on page 1 to “The 5P49V60 is a commercial, programmable clock generator supporting automotive applications” from “The 5P49V60 is a programmable clock generator intended for automotive applications.”</li> <li>Changed last bullet on front page to “-40°C to +105°C (Grade 2 equivalent) operating temperature” from “-40° to +105°C (Grade 2) temperature operation”.</li> </ul> |
| -        | Mar 16, 2021 | Updated the figure <a href="#">Overdriving XIN with an LVPECL Driver</a>   |
| -        | Jan 26, 2021 | Updated links to all VersaClock 6E Family Register Descriptions and Programming Guide references.<br>Added note and document link in section <a href="#">SD/OE Pin Function</a> under item 2.  |
| -        | Dec 10, 2020 | Updated text for clock slew rate values in the section “Driving XIN/REF with a CMOS Driver”.   |
| -        | Sep 4, 2020  | Updated pin 4 description.<br>Updated VIH minimum value.<br>Updated the section <a href="#">Driving XIN/REF with a CMOS Driver</a> .   |
| -        | Aug 20, 2020 | Updated the slew rate terminology in section <a href="#">Driving XIN/REF with a CMOS Driver</a> .  |
| -        | Oct 14, 2019 | Added PCIe Gen4 to Typical Applications.   |
| -        | Mar 8, 2019  | Updated package outline drawings.  |
| -        | Feb 22, 2019 | Updated marking diagram.   |
| -        | Jul 12, 2018 | Initial release.   |



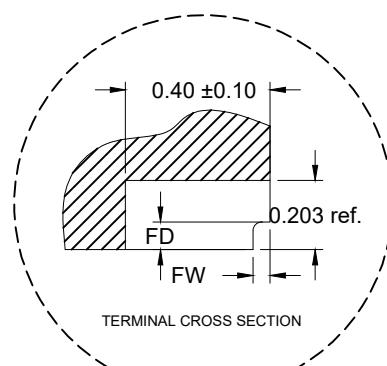
TOP VIEW



BOTTOM VIEW



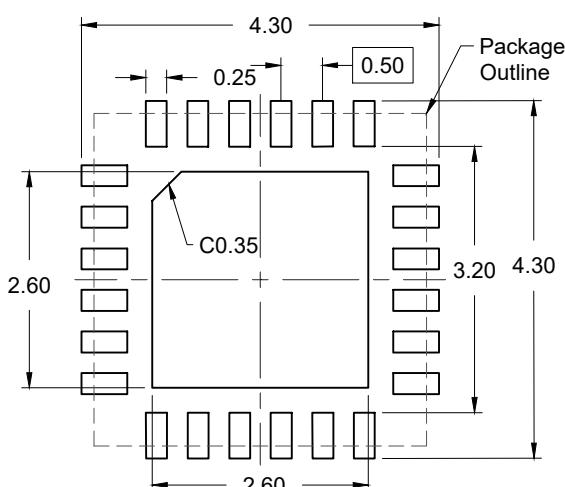
SIDE VIEW



DETAIL A

Table 1: Dimensions of wettable flank (DETAIL A)

| Symbol | Unit (mm) |       |
|--------|-----------|-------|
|        | MIN       | MAX   |
| FD     | 0.100     | -     |
| FW     | 0.001     | 0.075 |


 RECOMMENDED LAND PATTERN  
 (PCB Top View, NSMD Design)

## NOTES:

1. JEDEC compatible.
2. All dimensions are in mm and angles are in degrees.
3. Use  $\pm 0.05$  mm for the non-toleranced dimensions.
4. Numbers in ( ) are for references only.
5. Wettable flank (step cut).

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